SURFACE MOUNT MONOLITHIC CHIP CAPACITORS

CERAMIC CHIP CAPACITORS SAFETY STANDARD APPROVED – 250VAC



GHM2000/3000 Series



FEATURES

- Chip monolithic ceramic capacitor for AC line
- Sn plated external electrodes allow mounting without silver compound solder.
- Reflow soldering

APPLICATIONS

Ideal use for X/Y capacitor (GHM3000) or noise filter (GHM2000) on switching power supply, ballast, telephone, facsimile, modem

GHM2143/2243

- NOT safety approved. Made to the standards of the electrical appliance and material control law of Japan, separated table 4.
- Rated voltage: 250VAC
- Test voltage

GHM2243: 1500VACrms, 60 sec. GHM2143: 575VACrms, 60 sec.

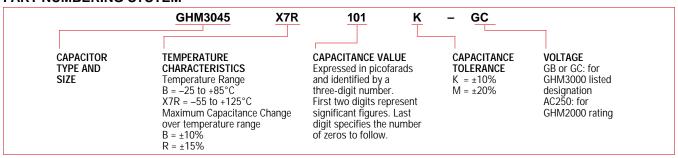
GHM3045

- Safety approved: VDE, SEV, SEMKO, BSI, and UL
- Rated voltage: 250VAC
- Test voltage: 1500VACrms, 60 sec.
- Recognized as X1/Y2 by IÉC384-14 2nd ed. (EN132400) and as line by-pass by UL1414

GHM3145

- Safety approved: VDE, SEV, SEMKO
- Rated voltage: 250VAC
- Test voltage: 1075VDC, 60 sec.
- Recognized as X2 by IEC384-14 2nd ed. (EN132400)

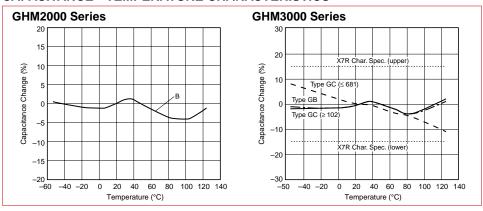
PART NUMBERING SYSTEM



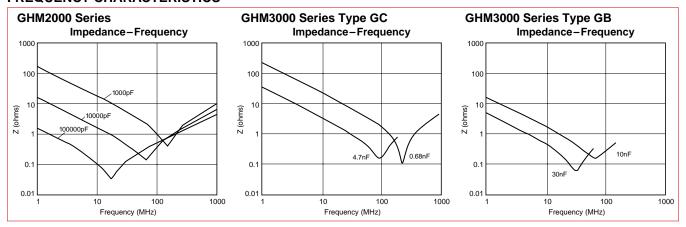
DIMENSIONS: mm

g min. e min.

CAPACITANCE - TEMPERATURE CHARACTERISTICS



FREQUENCY CHARACTERISTICS



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SURFACE MOUNT MONOLITHIC CHIP CAPACITORS CERAMIC CHIP CAPACITORS SAFETY STANDARD APPROVED-250VAC



GHM2000/3000 Series

GHM21□□ (Line to Line Capacitor) NOT Safety Approved

5	5 (1)		Capacitance	Dimensions: mm					AC Rated	Packaging Quantity
Part Nu	imber	Capacitance (pF)	Tolerance	L	W	T	g	е	Voltage [V(r.m.s.)]	(pcs/reel)
GHM2143B1	03MAC250	10000		5.7 ± 0.4	2.8 ± 0.3		3.5	0.3	250	1000
GHM2143B2	23MAC250	22000	±20%			2.0 ± 0.3				
GHM2143B4	73MAC250	47000	±2U/0	3.7 ± 0.4		2.0 ± 0.3	3.5	0.3	250	1000
GHM2145B1	04MAC250	100000			5.0 ± 0.4					

GHM22 (Line to Earth Capacitor) NOT Safety Approved

5	Nominal	Capacitance		Di	mensions: m	m		AC Rated	Packaging Quantity
Part Number	Capacitance (pF)	Tolerance	L	W	T	g	е	Voltage [V(r.m.s.)]	(pcs/reel)
GHM2243B471MAC2	50 470		5.7 ± 0.4	2.8 ± 0.3			0.3	250	1000
GHM2243B102MAC2	50 1000	±20%			2.0 ± 0.3	3.5			
GHM2243B222MAC2	50 2200	±2070			2.0 ± 0.3	5.5			
GHM2243B472MAC2	50 4700								

GHM3045 (X1, Y2)

5	Nominal Capacitance (pF)	Capacitance	Dimensions: mm					Rated	Packaging Quantity
Part Number		Tolerance	L	W	T	g	e	Voltage (VAC)	(pcs/reel)
GHM3045X7R101K-GC	100								
GHM3045X7R151K-GC	150								
GHM3045X7R221K-GC	220		5.7 ± 0.4	5.0 ± 0.4	2.0 ± 0.3	4.0	0.3	250	1000
GHM3045X7R331K-GC	330								
GHM3045X7R471K-GC	470								
GHM3045X7R681K-GC	680	±10%							
GHM3045X7R102K-GC	1000								
GHM3045X7R152K-GC	1500								
GHM3045X7R222K-GC	2200								
GHM3045X7R332K-GC	3300								
GHM3045X7R472K-GC	4700								

GHM3145 (X2)

D . N . I	Nominal				Capacitance	Dimensions: mm					Rated	Packaging Quantity
Part Number	Capacitance (pF)	Tolerance	L	W	Т	g	е	Voltage (VAC)	(pcs/reel)			
GHM3145X7R103K-GB	10000		5.7 ± 0.4	5.0 ± 0.4	2.0 ± 0.3	4.0	0.3	250	1000			
GHM3145X7R153K-GB	15000	+10%										
GHM3145X7R223K-GB	22000	±1U70										
GHM3145X7R333K-GB	33000				2.7 ± 0.3				500			

APPROVAL STANDARDS AND RECOGNIZED NUMBERS GHM3045 GHM3145

	Standard Number	Recognized Number	
UL	UL1414 (Line By Pass)	E37921	
SEMKO	IEC384-14 2nd Edition	9614021 01	
SEV VDE	(EN132400)	96.1 10333.02	
	(EN 132400) CLASS X1/Y2	94671	
BSI	CLASS X 1/12	228163	

	Standard Number	Recognized Number	
SEMKO	IEC384-14 2nd Edition	9614020 01	
SEV	(EN132400)	96.1 10333.02	
VDE	CLASS X2	94729	

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SURFACE MOUNT MONOLITHIC CHIP CAPACITORS SPECIFICATIONS AND TEST METHODS



GHM2000/3000 Series

No.	Item		Specification	Test Method			
1	Operating Tempe	erature Range	GHM2000: -25 to +85°C GHM3000: -55 to +125°C		_		
2	Dielectric Strength		Dielectric Strength No defects or abnormalities.		No failure shall be observed when voltage as table is applied between the terminations for 60 ± 1 s, provided the charge/discharge current is less than 50mA.		
				GHM21□□	Test Voltage		
					AC575V(r.m.s.)		
					GHM22□□	AC1500V(r.m.s.)	
				GHM3000 Type GB GHM3000 Type GC	1075VDC AC1500V(r.m.s.)		
3	Insulation Resist	tance (I.R.)	GHM2000: >2000M ohms GHM3000: >6000M ohms	The insulation resistance shall be within 60 ± 5 s of charging.	e measured with 500 \pm 50V and		
4	Capacitance		Within the specified tolerance.	The capacitance/D.F. shall be me 1 ± 0.2kHz and a voltage of 1 ± 0	easured at 20°C at a frequency of		
5	Dissipation Factor	or (D.F.)	0.025 max.	T ± 0.2KHz and a voltage of T ± 0	0.24(1.111.3.)		
6	Capacitance Tem Characteristics	nperature	Cap. Change GHM2000: ±10% GHM3000: ±15%	The range of capacitance change compared with the 20°C value within -25 to $+85$ °C (-55 to $+125$ °C for GHM3000) shall be within the specified range. Pretreatment Perform a heat treatment at 150^{+0}_{-10} °C for 60 ± 5 min. and then let sit for 24 ± 2 h at room condition.			
7	Discharge Test (Application: GHM22□□)	Appearance	No defects or abnormalities.	As in figure below, discharge is from the capacitor(Cd) charged R3	at DC voltage of specified.		
	(Application:	I.R.	More than 1000M ohms.				
	Type GC)	Dielectric Strength	See item 2.	Ct: Capacitor under test Cd: 0.001 µF R1: 1000 ohms R2: 100M ohms R3: Surge resistance			
8	Adhesive Strength of Termination		No removal of the terminations or other defects shall occur.	Solder the capacitor to the test ji Fig. 1 using a eutectic solder. Th	ig (glass epoxy board) shown in en apply 10N force in the ring shall be done either with an and shall be conducted with		
9	Vibration	Capacitance	Within the specified tolerance.	Solder the capacitor to the test ji	ig (glass epoxy board).		
	Resistance D.F.		0.025 max.	The capacitor shall be subjected having a total amplitude of 1.5m uniformly between the approxim frequency range, from 10 to 55l-traversed in approximately 1 mir for a period of 2 h in each of 3 n (total of 6 h).	m, the frequency being varied ate limits of 10 and 55Hz. The tz and return to 10Hz, shall be n. This motion shall be applied nutually perpendicular directions		
10	Deflection		Deflection No cracking or marking defects shall occur.		g jig (glass epoxy board) shown Then apply a force in the		
			L x W Dimensions (mm) (mm) a b c d		direction shown in Fig. 3. The sol an iron or using the reflow methocare so that the soldering is unifor heat shock. 20 50 Pressurize speed: 1. R230 Pressurize Capacitance meter	Idering shall be done either with od and shall be conducted with orm and free of defects such as zing .0mm/s	
11	Solderability of	Termination	75% of the terminations are to be soldered evenly and continuously.		ion of ethanol (JIS-K-8101) and n weight proportion). on for 2 ± 0.5 s at 235 ± 5°C.		

SURFACE MOUNT MONOLITHIC CHIP CAPACITORS SPECIFICATIONS AND TEST METHODS



CG01-H

GHM2000/3000 Series

No.	It	em	Specification	Test Method					
12	Resistance to Soldering	Capacitance Change	Within ±10%	Preheat the capacitor as table. Immerse the capacitor in eutectic solder solution at 260 \pm 5°C for 10 \pm 1 s. Let sit at room					
	Heat	I.R.	GHM2000: >2000M ohms GHM3000: >1000M ohms	condition for 24 ± 2 h, then measure. Immersing speed: 25 ± 2.5mm/s Pretreatment					
		Dielectric Strength	See item 2.	Perform a heat treatment at 150^{+0}_{-10} °C for 60 ± 5 min. and ther let sit for 24 ± 2 h at room condition. *Preheating					
				Step Temperature Time					
				1 100°C to 120°C 1 min 2 170°C to 200°C 1 min					
13	Temperature Cycle	Capacitance Change	GHM2000: within ±7.5% GHM3000: within ±15%	Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig. 4 using a eutectic solder.					
		D.F.	GHM2000: 0.025 max. GHM3000: 0.05 max.	Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24 ± 2 h at room condition, then measure.					
		I.R.	GHM2000: >2000M ohms GHM3000: >3000M ohms	Step Temperature (°C) Time (min) 1 Min. Operating Temp. ±3 30 ± 3					
		Dielectric	See item 2.	2 Room Temp. 2 to 3					
		Strength		3 Max. Operating Temp. ±2 30 ± 3 4 Room Temp. 2 to 3					
				Pretreatment Perform a heat treatment at 150 +0 o C for 60 ± 5 min. and then let sit for 24 ± 2 h at room condition. Solder Resist Glass Epoxy Board Fig. 4					
14	4 Humidity (Steady State)	Capacitance Change	Within ±15%	Sit the capacitor at $40 \pm 2^{\circ}$ C and relative humidity 90 to 95% fo 500^{+24} h.					
		D.F.	0.05 max.	Remove and let sit for 24 ± 2 h at room condition, then measure. Pretreatment					
		I.R.	GHM2000: >1000M ohms GHM3000: >3000M ohms	Perform a heat treatment at 150^{+0}_{-10} °C for 60 ± 5 min. and then let sit for 24 ± 2 h at room condition.					
		Dielectric Strength	See item 2.						
15	Life	Capacitance Change	GHM2000: ±15% GHM3000: ±20%	GHM2000: Apply voltage and time as Table at 85 ± 2°C. Remove and let sit for 24 ± 2 h at room condition, then measure. The charge/discharge current is less than 50mA.					
		D.F.	0.05 max.	Test Time Test Voltage					
		I.R.	GHM2000: >1000M ohms GHM3000: >3000M ohms	GHM21□□ 1000 ⁺⁴⁸ ₋₀ h AC300V(r.m.s.) GHM22□□ 1500 ⁺⁴⁸ ₋₀ h AC500V(r.m.s.)*					
		Dielectric Strength	See item 2.	*Except that once each hour the voltage is increased to AC1000V(r.m.s.) for 0.1 s. Pretreatment Apply test voltage for 60 ± 5 min. at test temperature.					
				GHM3000: Impulse Voltage Each individual capacitor shall be subjected to a 2.5kV (Type GC: 5kV) Impulse (the voltage value means zero to peak) for three times. Then the capacitors are applied to life test. Apply voltage as Table for 1000 h at $125 \stackrel{+0}{-}^{\circ}$ C, relative humidition.					
				Type Applied Voltage GR AC312.5V(r.m.s.), except that once each hour the					
				GB AC425V(r.m.s.), except that once each floor the voltage is increased to AC1000V(r.m.s.) for 0.1 s. AC425V(r.m.s.), except that once each hour the voltage is increased to AC1000V(r.m.s.) for 0.1 s.					
16	Humidity	Appearance	No marking defects.	Apply the rated voltage at 40 ± 2°C and relative humidity 90 to					
	Loading	Capacitance Change	Within ±15%	95% for 500 +24h. Remove and let sit for 24 ± 2 h at room condition, then measure. Pretreatment					
		D.F.	0.05 max.	Apply test voltage for 60 ± 5 min. at test temperature.					
		I.R.	GHM2000: >1000M ohms GHM3000: >3000M ohms	Remove and let sit for 24 ± 2 h at room condition.					
		Dielectric Strength	See item 2.						